Optical Properties of Solids: Lecture 6

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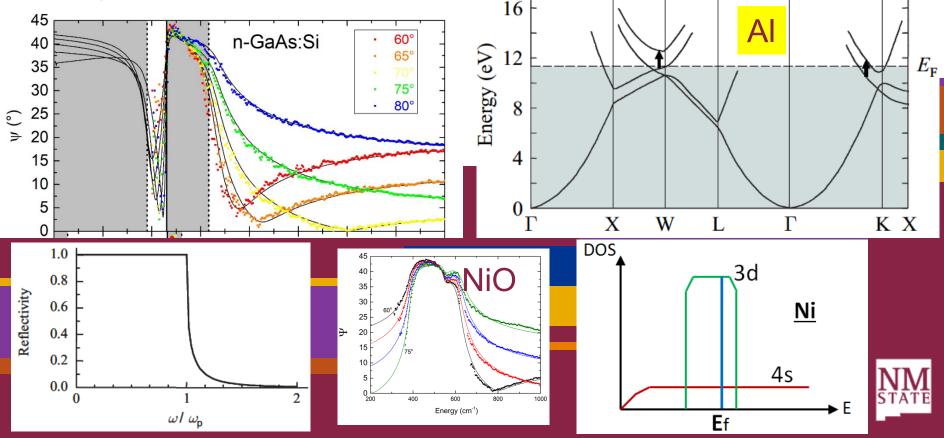
NSF: DMR-1505172



http://ellipsometry.nmsu.edu

Optical Properties of Solids: Lecture 5+6

- Lorentz and Drude model: Applications
- 1. Metals, doped semiconductors
- 2. Insulators
- Sellmeier equation, Poles, Cauchy dispersion Analytical properties of ϵ



References: Dispersion, Analytical Properties

Standard Texts on Electricity and Magnetism:

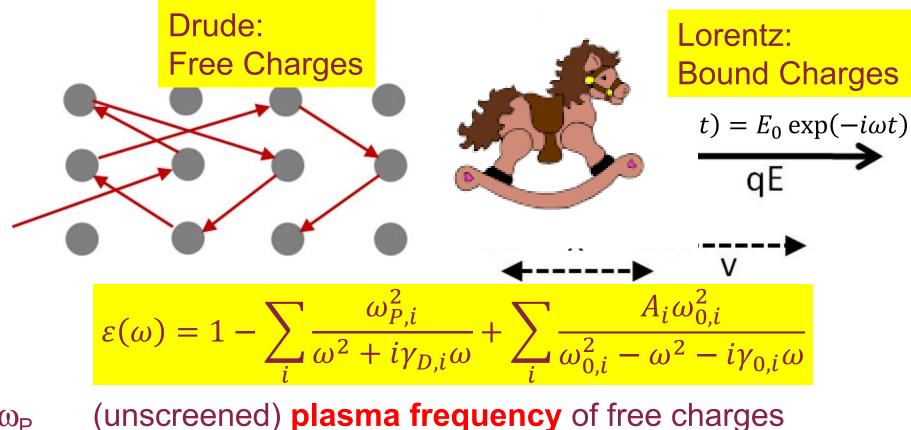
- J.D. Jackson: *Classical Electrodynamics*
- L.D. Landau & J.M. Lifshitz, Vol. 8: *Electrodynamics of Cont. Media*

Ellipsometry and Polarized Light:

- R.M.A. Azzam and N.M. Bashara: *Ellipsometry and Polarized Light*
- H.G. Tompkins and E.A. Irene: Handbook of Ellipsometry (chapters by Rob Collins and Jay Jellison)
- H. Fujiwara, Spectroscopic Ellipsometry
- Mark Fox, Optical Properties of Solids
- H. Fujiwara and R.W. Collins: Spectroscopic Ellipsometry for PV (Vol 1+2)
- Zollner: *Propagation of EM Waves in Continuous Media* (Lecture Notes)
- Zollner: Drude and Kukharskii mobility of doped semiconductors extracted from FTIR ellipsometry spectra, J. Vac. Sci. **37**, 012904 (2019).



Drude-Lorentz Model: Free and Bound Charges



- $\omega_{\rm P}$ (unscreened) plasma frequency of free charges ω_0 resonance frequency of bound charges
- γ_D , γ_0 broadenings of free and bound charges
- A **amplitude** of bound charge oscillations (density, strength)

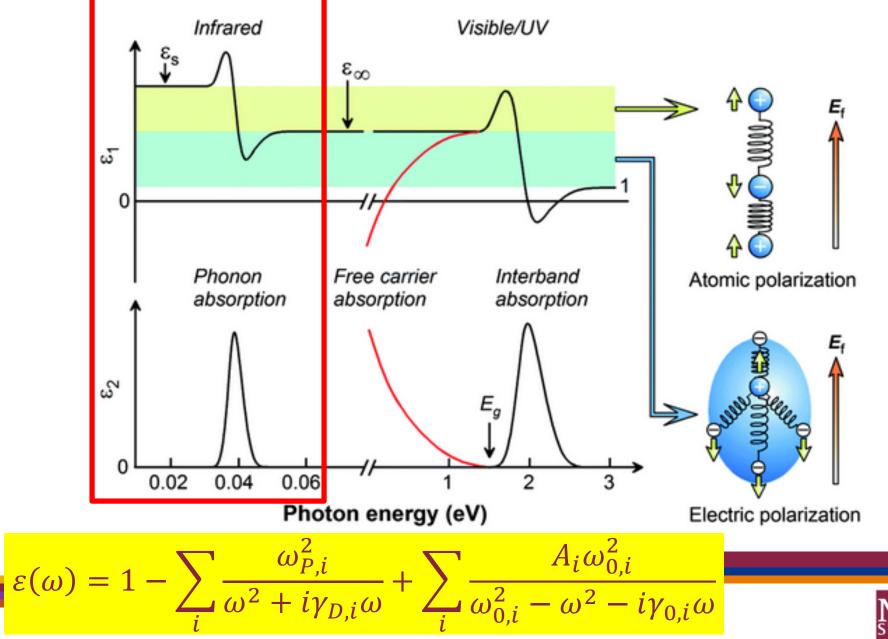
Discuss plasma frequency trends.

 $n_f e^2$

me



Drude-Lorentz Model: Free and Bound Charges



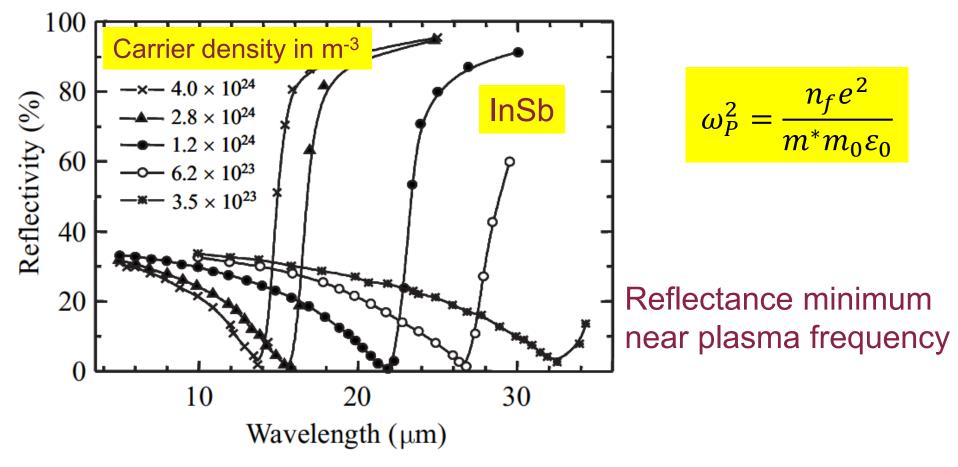
Semiconductors

	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	
1	1 ¹ H Hydrogen 1.00794	Atomic #	C Solid			Metals					Nonmetals								К
2	3 7 Li Lithium 6.941	4 2 Be Berylium 9.012182	Hg Liquid H Gas Rf Unknown			Alkali metals	hme	anthanoids metals		Poor metals	Other	Noble ga	5 B Boron 10.811	6 2 Carbon 12.0107	7 g N Nitrogen 14.0057	8 ² 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0	9 # F Fluorine 18.9984032	10 8 Ne 20.1797	K L
3	11 Sodium 22.95976928	12 20 Mg Magnesium 24.3060				Actinoids 3					gases etals		13 Al Aluminium 26.9815386	14 Si Silcon 28.0855	15 3 P Phosphorus 30.973762	16 8 Sulfur 32.065	17 27 Cl Chiome 35,453	18 28 Ar Argon 39.948	×-1
4	19 8 K Potassium 39.0963	20 Ca Calcium 40.078	21 50 Scandum 44.955912	22 28 Ti Titanium 47.887	23 11 Vanadium 50.9415	24 28 Cr 13 Chromium 51.9981	25 5 Mn Marganese 54.938045	26 8 Fe 12 Iron 55.845	27 te	28 Ni Nickel 58.8934	29 Cu Copper 63.546	30 ⁸ Zn ² ^{2ino} 65.38	31 Ga Gallum 69.723	32 Ge Gemanium 72.84	33 2 As ¹⁸ Arsenic 74.62180	34 ² Seenium 78.96	35 a Br Bromine 79.904	36 18 Kryston 83.798	KLMN
5	37 88 Rb Rubidium 85.4878	38 Sr Strontium 87.02	39 18 Y 1510m 88.90585	40 38 39 20 20 20 20 20 20 20 20 20 20 20 20 20	41 18 Nobium 92,90038	42 Mo Molybdenum 95.96	43 Tc (97.9072)	44 88 18 18 18 18 18 18 18 18 18 18 18 18	45 Rh 102.90550	46 Pd Paladium 106.42	47 Ag Skver 107.8682	48 18 Cd 19 Cadmium 112.411	49 In Indium 114.818	50 50 Sn 10 Tin 118.710	51 3 Sb 3 Antimony 121.780	52 58 Te 58 Telunum 127.60	53 8 18 100me 120.90447	54 18 Xe 18 Xenon 131.293	OKELN
6	55 22 Cs 18 Caesium 132.9054618	56 18 Ba 18 Balum 2 137,327	57–71	72 2 Hf 32 Hafnium 2 178.49	73 18 Ta 180.94788	74 28 W 18 Tungeten 183.84	75 20 Re 10 Rhenium 186.207	76 38 Os 32 Osmium 190.23	77 10 10 10 10 10 10 10 10 10 10 10 10 10	78 Pt 195.084	79 Au Gold 195 955559	80 10 10 10 10 10 10 10 10 10 10 10 10 10	81 53 Thailium 204,3833	Pb 15 Pb 15 Lead 4 207.2	83 2 Bi 32 Biemuth 5 208.98040	84 20 Polonium (208.9824)	85 18 At 18 Astatine (209.8871)	86 15 Rn 15 Radon (222.0176)	RUNNER
7	87 28 Fr 82 Francium 81 (223)	88 200 200 200 200 200 200 200 200 200 2	89–103	104 28 Rf 322 Rutertockm 12 (281)	105 18 Db 18 Dubnium 11 (282)	106 28 Sg 32 Seaborgium 22 (208)	107 28 Bh 322 Bohrium 12 (284) 22	108 18 Hs 18 Hassium 14 (277) 2	109 Mt 300 (266)	110 Ds Dametacium (271)	111 Rg Footgenum (272)	112 Uub Ununbium (285)	113 Uuut Ununtrium (214)	114 Uuq Uuvquadum (289)	115 Uup Unupertum (288)	116 Uuh Ununhexium (292)	117 Uus Uhurseptum	118 Uuo Ununoctium (294)	0.00225-2
For elements with no stable isotopes, the mass number of the isotope with the longest half-life is in parentheses.																			
				Design and Interface Copyright © 1997 Michael Dayah (michael@dayah.com). http://www.ptable.com/															
	Dta	bla		57 5 La 5 Lanthanum 138.90547	58 8 8 8 8 8 8 8 8 8 8 8 8 8 8 8 8 8 8	59 Pr Pasesstymum 140.90765	60 ⁷ Nd ¹⁵ Neodymium 144.242	61 53 Pm 53 Promethium 2 (145)	62 50 Sm 53 Samarium 150.36	63 Eu Europium 151.904	64 Gd Gadolinium 157.25	65 5 Tb 57 Terbium 158.92535	66 55 Dy Dysprosium 162,500	67 5 Ho 29 Holmum 164 93032	68 28 Er 30 Erbium 2 107.259	69 53 Tm 55 Thulium 108.93421	70 \$8 Yb \$10 173.054	71 Lu ¹⁸ Lutetium ¹⁰ 174.9008	
		com		89 28 Ac 35 Actinium 92 (227) 2	90 28 28 28 28 28 28 28 28 28 28 28 28 28	91 28 20 20 20 20 20 20 20 20 20 20 20 20 20	92 35 Uranium 238.02891	93 ²⁸ Np ³⁵ Neptunium ⁵² (237) ²	94 20 Pu 32 Pistonium 2 (244)	95 Am Americium (243)	96 Cm Curium (247)	97 28 Bk 30 (247) 27	98 Cf Californium (251)	99 28 Es 102 (252) 29	100 200 Fm 30 Fennium (257)	101 10 Md 30 Nendelevium 02 (258)	102 102 10 10 10 10 10 10 10 10 10 10 10 10 10	103 10 Lr 32 (252) 20 20 20 20 20 20 20 20 20 20 20 20 20 2	



STATE

Free-Carrier Reflection in doped semiconductors

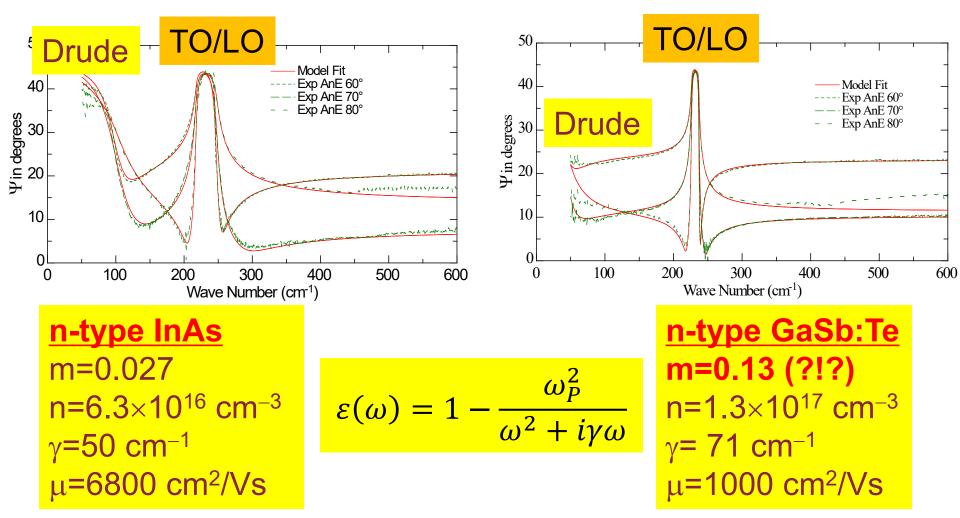


Doped semiconductors behave just like a metal, except for the lower carrier density; **plasma frequency in infrared region.**

Fox, Optical Properties of Solids

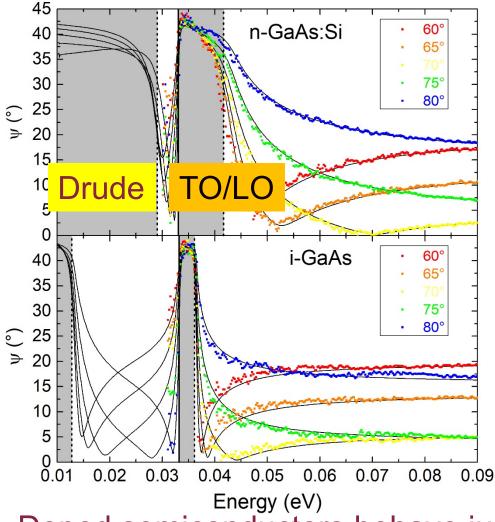


Infrared ellipsometry of doped semiconductors



Doped semiconductors behave just like a metal, except for the lower carrier density; plasma frequency in infrared region. Only visible for electrons (small mass). Stefan Zollner, February 2019, Optical Properties of Solids Lecture 6 8

Infrared ellipsometry of doped semiconductors



$$\varepsilon(\omega) = 1 - \frac{\omega_P^2}{\omega^2 + i\gamma\omega}$$

30 meV lower cut-off insufficient to see Drude term.

Plasmon effect:

Doping pushes LO phonon to

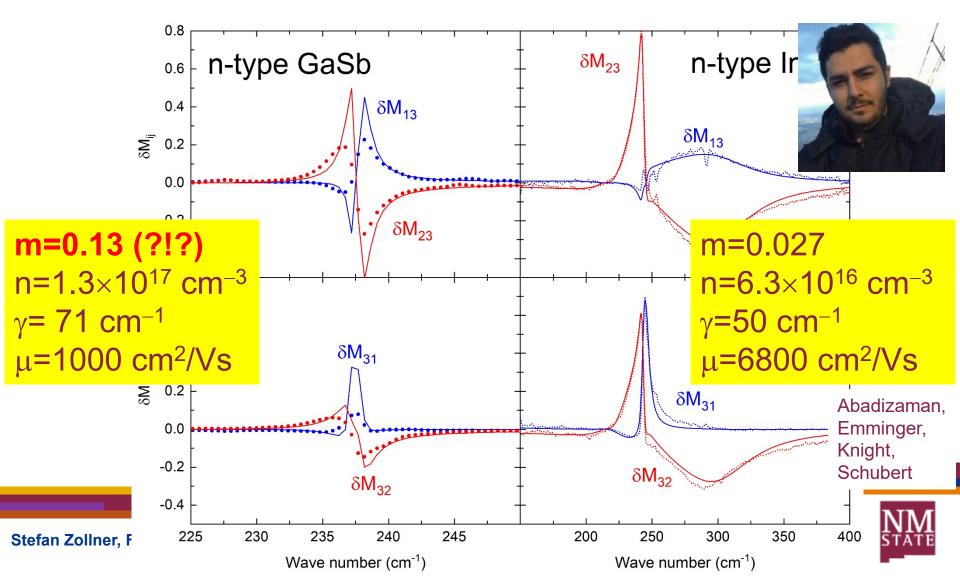
higher energies.



Doped semiconductors behave just like a metal, except for the lower carrier density; **plasma frequency in infrared region.**

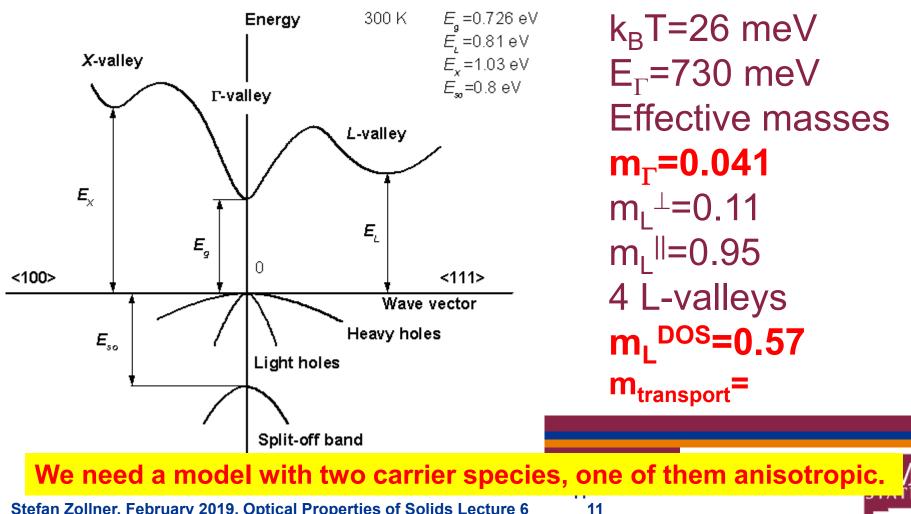
Optical Hall Effect: Ellipsometry with magnetic field

If we measure Mueller matrix spectra in a magnetic field, we get **carrier concentrations, mobilities, effective masses**.



Multi-valley semiconductors

GaSb is a direct semiconductor (like GaAs), but ALMOST indirect. The L-valley in GaSb is only 80 meV above the Γ -valley. Almost all electrons are in the L-valley at room temperature.

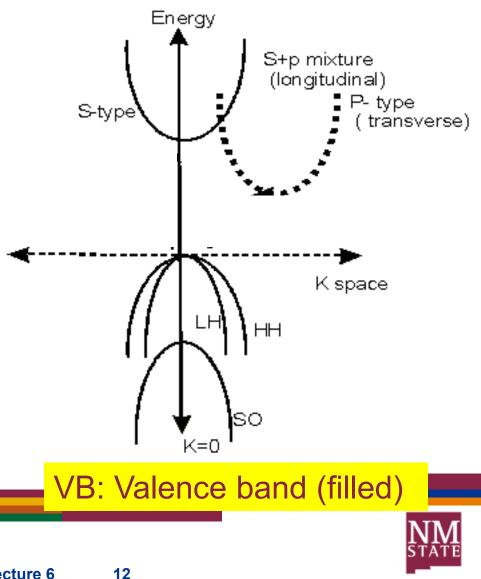


Multiple Drude Contributions

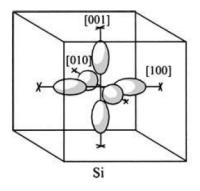
- Electron mass depends on orbital (s, p, d, f)
 s: light (small mass m*<<1)
 p: intermediate (m*~0.3 to 1)
 d,f: heavy (large mass m*>>1)
 p,d,f: usually anisotropic
- Electrons and holes
- Different CB minima (Γ,L,X)
- Different VB hole bands (light, heavy, split-off)

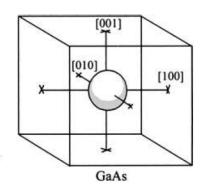
P. Drude, Phys. Z. 1, 161 (1900).

CB: Conduction band (empty)



Drude Model for Anisotropic Free Carriers





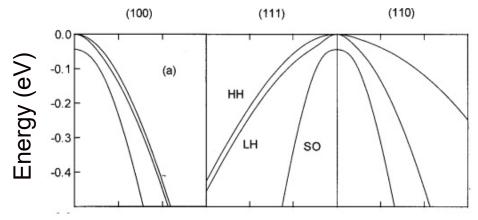
Conduction band minima in Ge and Si are anisotropic. Ge: m_1 =1.59, m_t =0.0815.

$$E(\vec{k}) = \frac{\hbar^2 \vec{k}^2}{2m}$$

$$m^{-1} = \frac{1}{\hbar^2} \frac{\partial^2 E(\vec{k})}{\partial \vec{k}^2} = \begin{pmatrix} m_l^{-1} & 0 & 0\\ 0 & m_t^{-1} & 0\\ 0 & 0 & m_t^{-1} \end{pmatrix}$$

$$m = \frac{m_l m_t}{m_t + 2m_l}$$

$$\Delta \text{-valley}$$
Drude mass Harmonic mean



Valence band maxima in semiconductors are warped (Luttinger parameters).

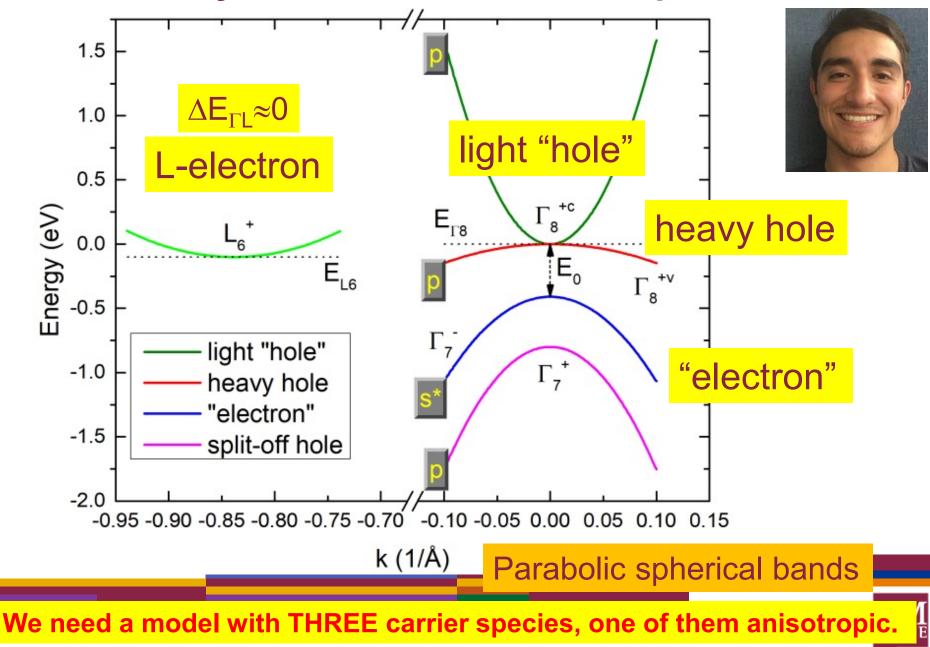
$$\varepsilon(\omega) = 1 - \frac{\omega_P^2}{\omega^2 + i\gamma\omega}$$
$$\omega_P^2 = \frac{nq^2}{m\varepsilon_0}$$
 Charge density

Drude formula still valid, but $\epsilon, \ \omega_p{}^2, \ m^{-1},$ and γ are tensors.

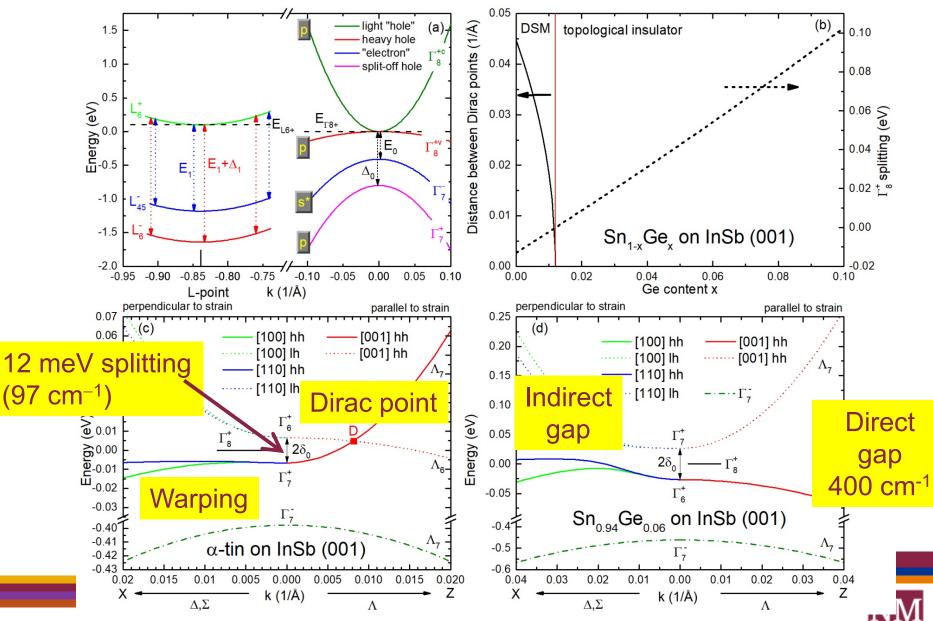
P. Drude, Phys. Z. 1, 161 (1900).



Grey α -tin is even more complicated



Add strain and warping in Sn_{1-x}Ge_x alloys



How do we model Drude response of free carriers with realistic band structures?

Semiclassical Model of Electron Dynamics

$$\dot{\vec{r}} = \vec{v}_n(\vec{k}) = \frac{\hbar \vec{k}}{m} = \frac{1}{\hbar} \frac{\partial E_n(\vec{k})}{\partial \vec{k}}$$

$$\dot{\vec{k}} = q[\vec{E}(\vec{r},t) + \vec{v}_n(\vec{k}) \times \vec{B}(\vec{r},t)]$$

$$f\left(E_n(\vec{k})\right) = \frac{1}{\exp[(E_n(\vec{k}) - E_F)/k_BT] + 1}$$

$$m_c(E,k_z) = \frac{\hbar^2}{2\pi} \frac{\partial A(E,k_z)}{\partial E}$$

"Electrons move along curves given by the intersection of surfaces of constant energy with planes perpendicular magnetic field." Is there an **optical analog to Shubnikov-de Haas effect? (Ge-Sn, GaSb)**

How do we model Drude response of free carriers with realistic band structures?

Anisotropic masses (GaSb L-valley)

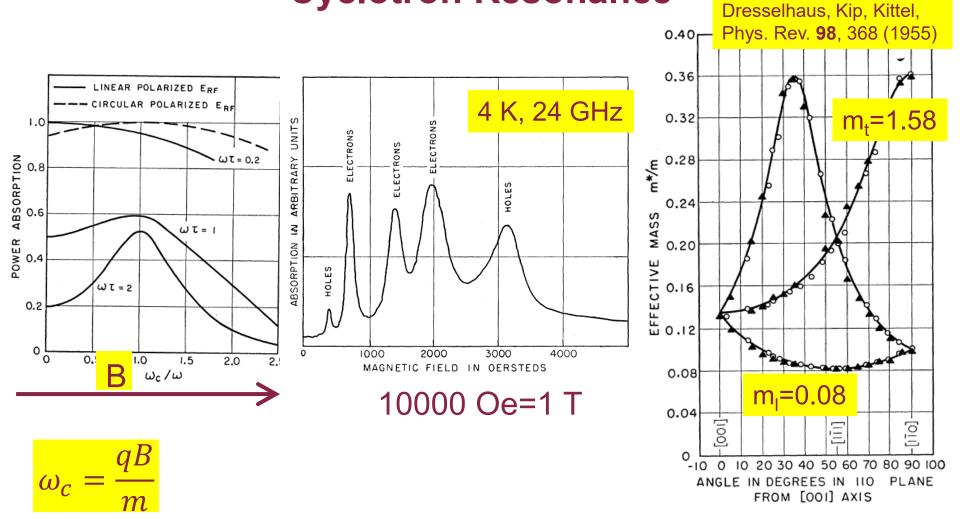
- Longitudinal mass at L Transverse mass at L
- Density of states mass (geometric mean)
- **Drude transport mass** (harmonic mean)
- Cyclotron mass

- $m_1 = 0.95$ m_t=0.11 $m_d = \sqrt[3]{N_V^2 m_l m_t^2}$ m_d=0.57 **m**_D=0.15 $\frac{3}{m_D} = \frac{1}{m_l} + \frac{2}{m_t}$ $m_c = \sqrt{\frac{\det \vec{m}}{\vec{b} \cdot \vec{m} \cdot \vec{b}}}$
- Optical Hall effect measurements on anisotropic materials are sparse. Need measurements on bulk Si, Ge, GaP with different orientations (change direction of magnetic field). How about SiC?

Dresselhaus, Dresselhaus, Cronin, Gomes, Solid-State Properties (10.50)



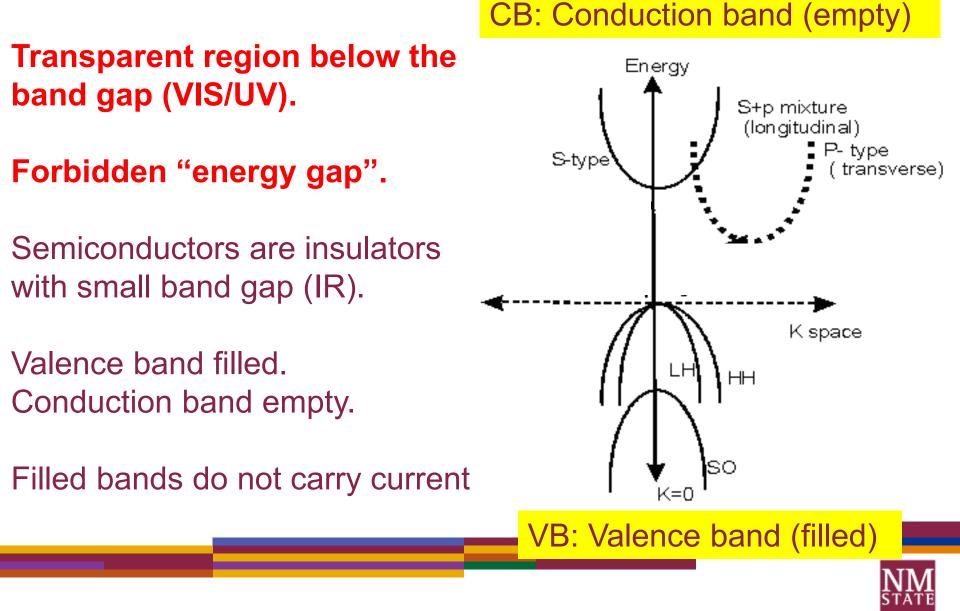
Cyclotron Resonance



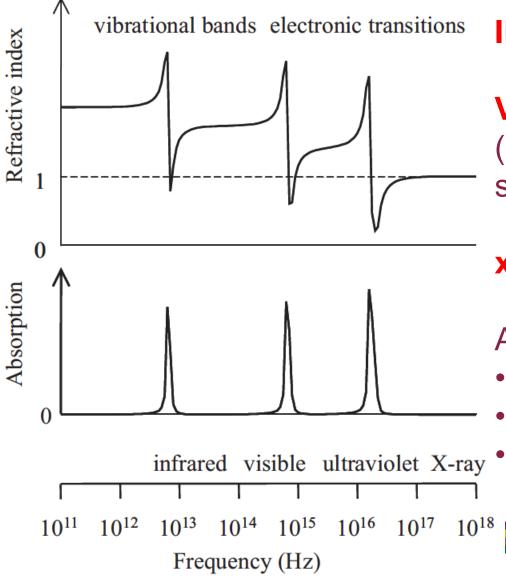
Measure microwave absorption as a function of the magnetic field. Information about VB warping.



Insulators



Multiple Lorentz Contributions: IR, UV, x-ray



IR: lattice vibrations

VIS/UV: valence electrons (usually broadened by band structure effects)

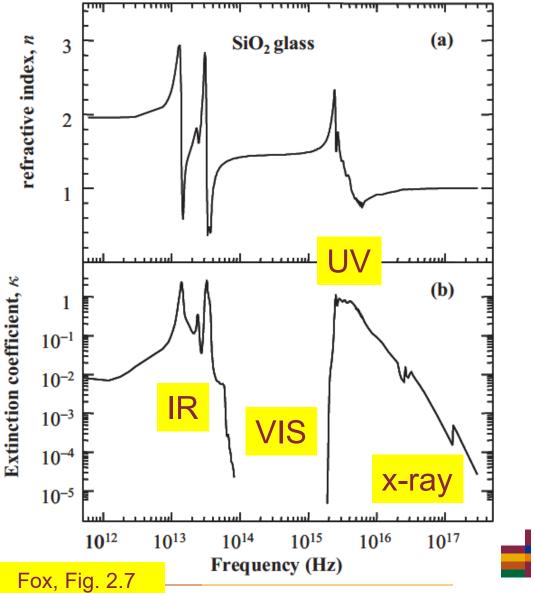
x-ray: core electrons

Amplitude depends on

- Density of oscillators
- Matrix elements
- Born effective charge

Fox, Fig. 2.6

Multiple Lorentz Contributions: SiO₂ as an Example



IR: lattice vibrations (Si-O bend, stretch)

VIS: Nothing happens

UV: valence electrons (interband transitions)

x-ray: core electrons (absorption edges)

Amplitude depends on

- Density of oscillators
- Matrix elements
- Born effective charge



Poles, Sellmeier Approximation

Refractive index

Set γ =0 far from resonance. Lorentz oscillator becomes a **pole**

$$\varepsilon(\omega) = 1 + \frac{A\omega_0^2}{\omega_0^2 - \omega^2}$$

Rewrite as a function of λ

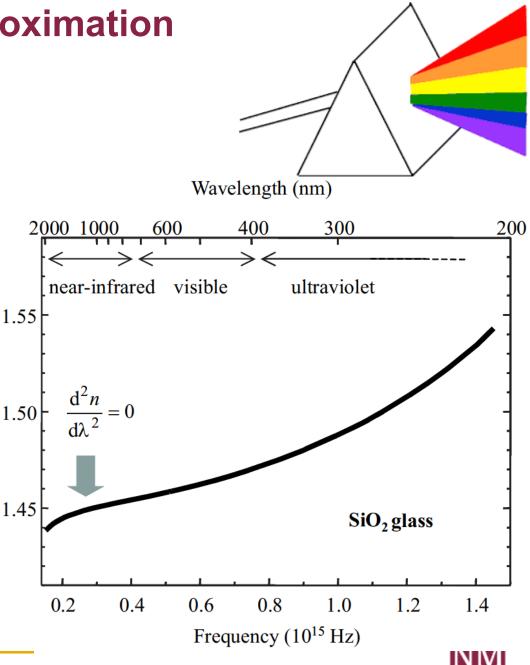
$$\varepsilon(\lambda) = 1 + \frac{B\lambda^2}{\lambda^2 - C}$$

Several Lorentz oscillators (one in IR, two in UV)

$$\varepsilon(\lambda) = 1 + \sum_{i} \frac{B_i \lambda^2}{\lambda^2 - C_i}$$

Sellmeier approximation.

Stefan Zollner, February 2019, Optical Properties of Solids Lecture 6



Fox, Fig. 2.10

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Cauchy Equation (Urbach Tail)

The Cauchy equation

$$n(\lambda) = \sqrt{\varepsilon(\lambda)} = A + \frac{B}{\lambda^2} + \frac{C}{\lambda^4}$$

can be viewed as a Laurent series expansion of the Sellmeier equation

$$n(\lambda) = \sqrt{\varepsilon(\lambda)} = \sqrt{1 + \frac{B\lambda^2}{\lambda^2 - C}}$$

Comments:

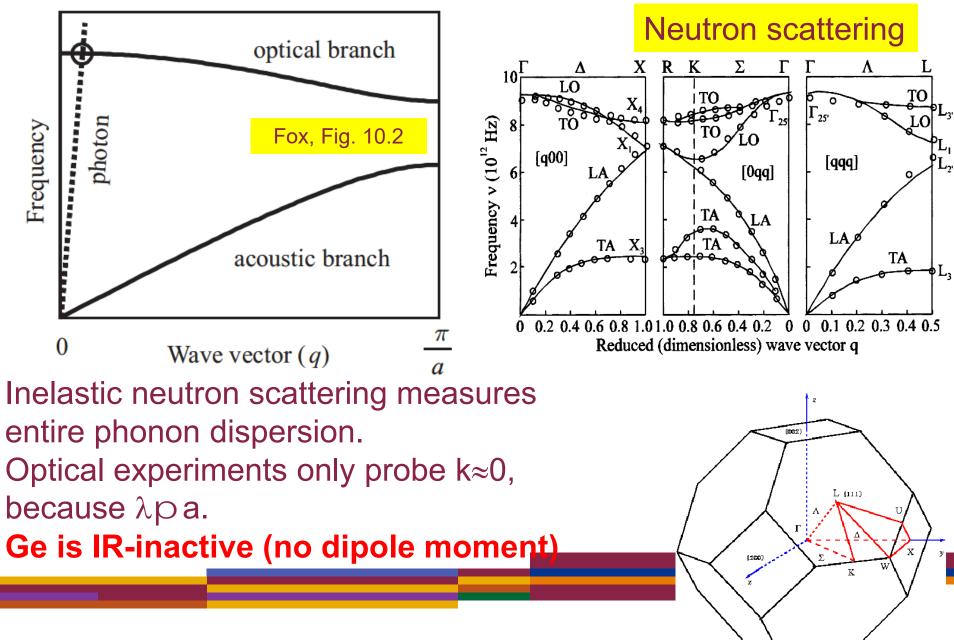
The Cauchy equation does not include absorption and therefore is not Kramers-Kronig consistent. Absorption is often included with an Urbach tail

$$k(E) = \alpha e^{\beta(E-\gamma)}$$

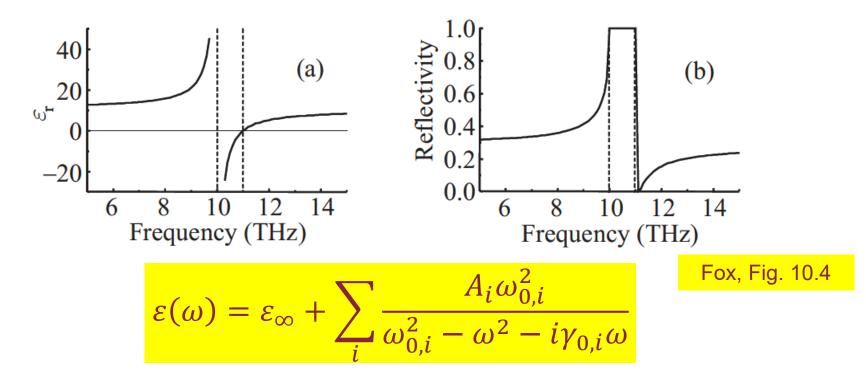
but this still does not make it Kramers-Kronig consistent. Not recommended, use Tauc-Lorentz model instead.



Insulator Phonon Spectra (Ge)



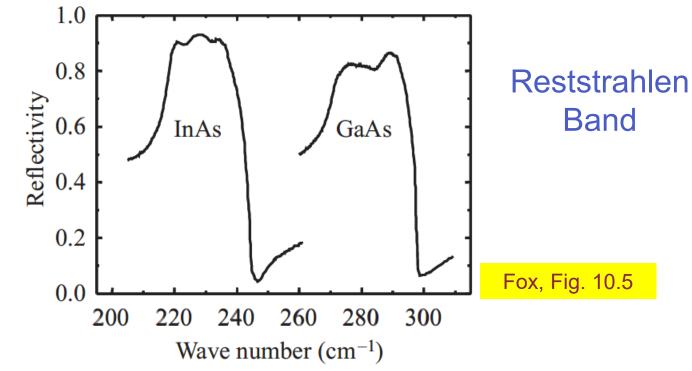
Infrared Lattice Vibrations (Lorentz model)



In **polar materials** (Born effective charge), TO and LO modes are split. TO: transverse optical (displacement perpendicular to **k**) LO: longitudinal optical (displacement along **k**) ε_2 has peak at TO frequency ε_1 is negative from TO to LO frequency (reflectance is 1)



Infrared Lattice Vibrations (Lorentz model)

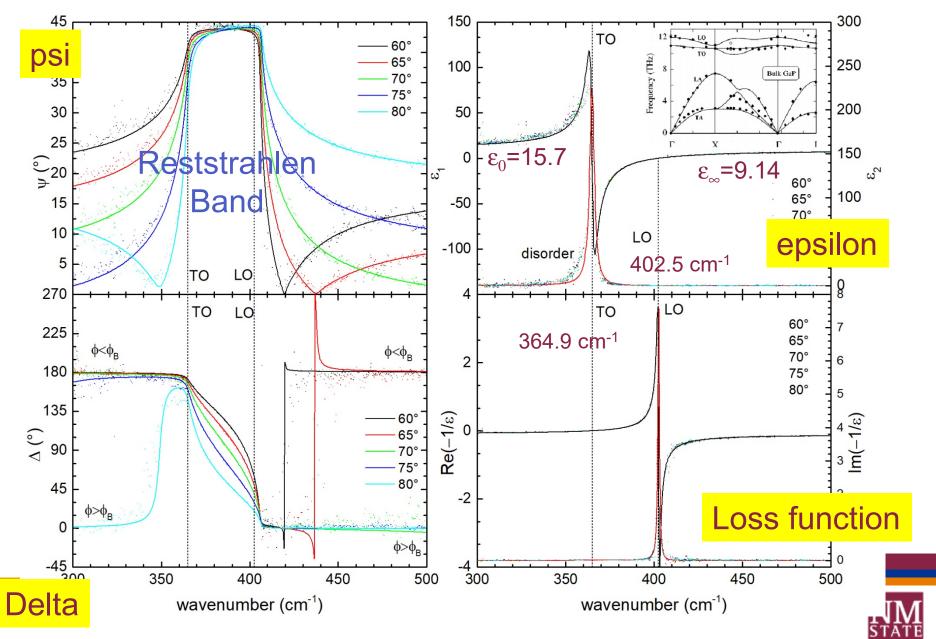


In polar materials (Born effective charge), TO and LO modes are split. TO: transverse optical (atomic displacement perpendicular to **k**) LO: longitudinal optical (atomic displacement along **k**) ε_2 has peak at TO frequency ε_1 is negative from TO to LO frequency (reflectance is 1) Restrahlen band extends from TO to LO energy.

$$\varepsilon(\omega) = \varepsilon_{\infty} + \frac{A\omega_0^2}{\omega_0^2 - \omega^2 - i\gamma_0\omega}$$
ids Lecture 6 26

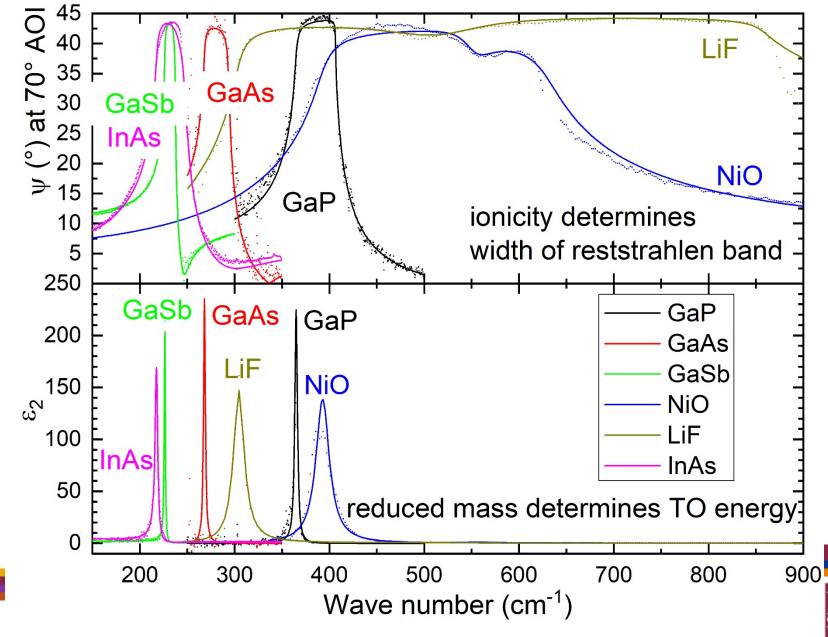


Infrared Lattice Vibrations in GaP

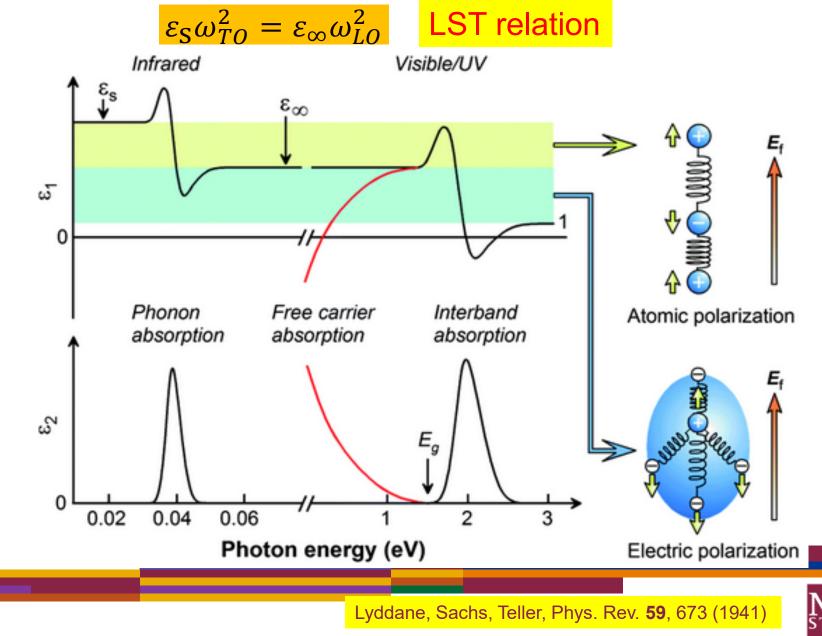


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Infrared Lattice Vibrations (Lorentz model)



Lyddane Sachs Teller relation (Lorentz model)



Lyddane Sachs Teller relation (Lorentz model)

Lorentz model (γ =0) for one TO/LO phonon mode

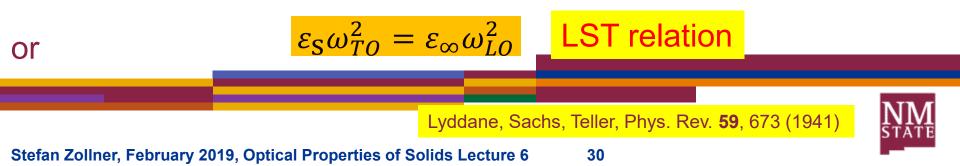
$$\varepsilon(\omega) = \varepsilon_{\infty} + \frac{A\omega_0^2}{\omega_0^2 - \omega^2}$$

At zero frequency (ω =0) define static dielectric constant ϵ_s

$$\varepsilon_{\rm S} = \varepsilon(\omega = 0) = \varepsilon_{\infty} + A$$

Define ω_{LO} through $\varepsilon(\omega_{LO})=0$ (Longitudinal modes require $\varepsilon=0$).

$$0 = \varepsilon_{\infty} + \frac{A\omega_0^2}{\omega_0^2 - \omega_{LO}^2}$$



Generalized Lyddane Sachs Teller relations

Multiple phonon modes (isotropic)

$$\frac{\varepsilon_{\rm S}}{\varepsilon_{\infty}} = \prod_{i} \frac{\omega_{LO,i}^2}{\omega_{TO,i}^2}$$

Kurosawa, J. Phys. Soc. Jpn. **16**, 1298 (1961)

Anisotropic crystals

$$\frac{\det(\varepsilon_{\rm S})}{\det(\varepsilon_{\infty})} = \prod_{i} \frac{\omega_{LO,i}^2}{\omega_{TO,i}^2}$$

Mathias Schubert, Phys. Rev. Lett. 117, 215502 (2016)

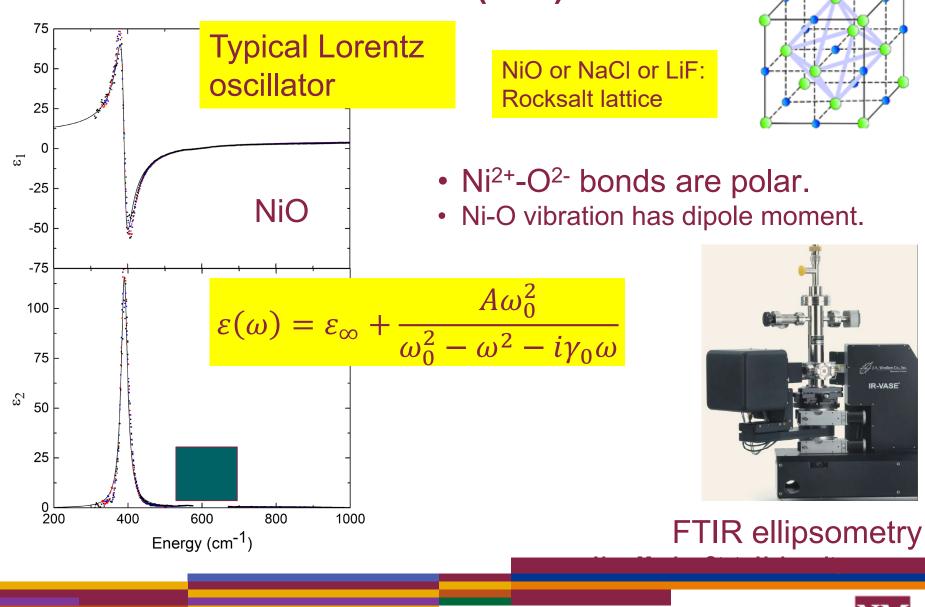
Amorphous materials and liquids

$$\frac{\varepsilon_{\rm S}}{\varepsilon_{\infty}} = \frac{\langle \omega^2 \rangle_l}{\langle \omega^2 \rangle_t}$$

A.J. Sievers and J.B. Page, Infrared Physics **32**, 425 (1991)



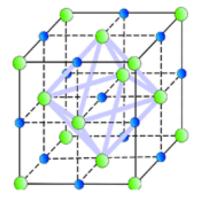
Infrared Lattice Vibrations (NiO)



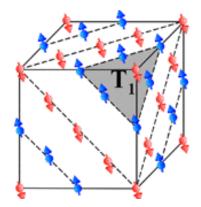


Infrared Lattice Vibrations (NiO)

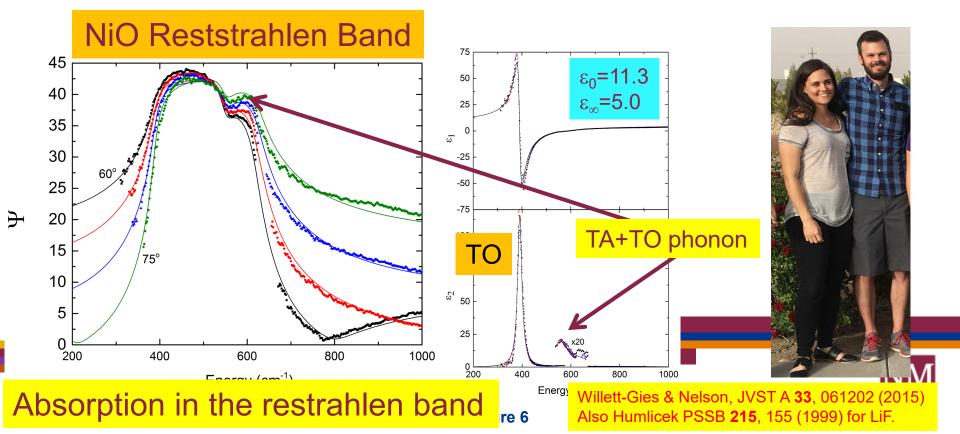
- •Rocksalt Crystal Structure (FCC), Space Group 225 (Fm-3m).
- Single TO/LO phonon pair.
- •Antiferromagnetic ordering along (111), should cause phonon splitting (8-30 cm⁻¹).
- Second-order phonon absorption.



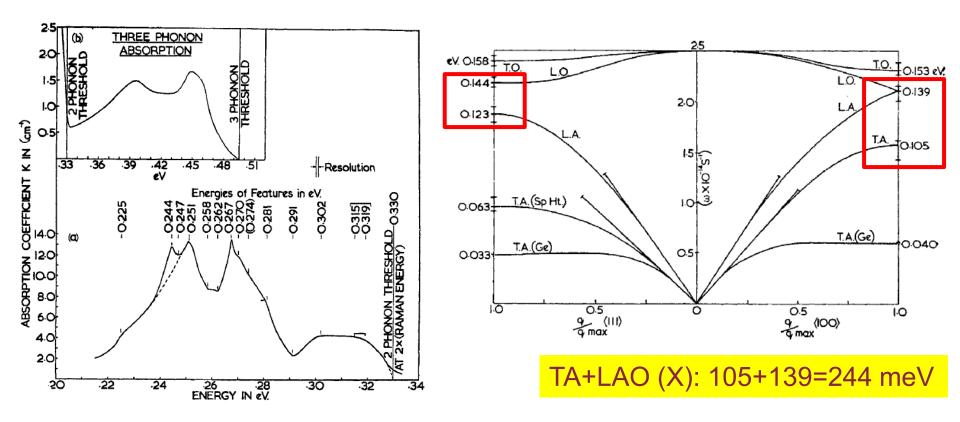
NiO cell







Two-phonon absorption (diamond)

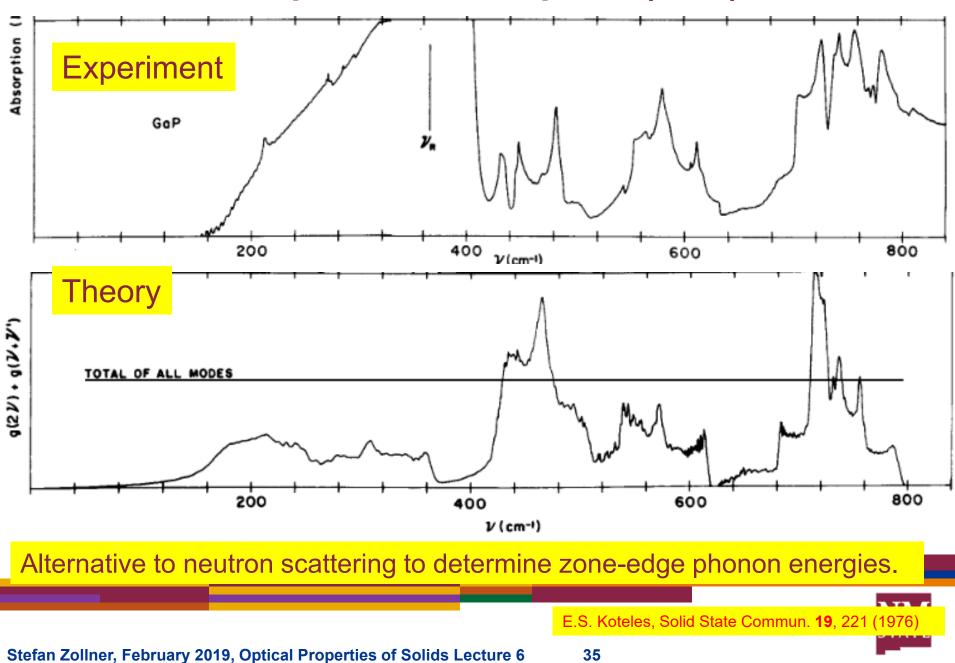


A single photon excites two phonons. Energy and wave vector conserved. Two-phonon absorption is weak (lower probability than TO phonon absorption). Most likely to occur near Brillouin zone boundary (high density of states).

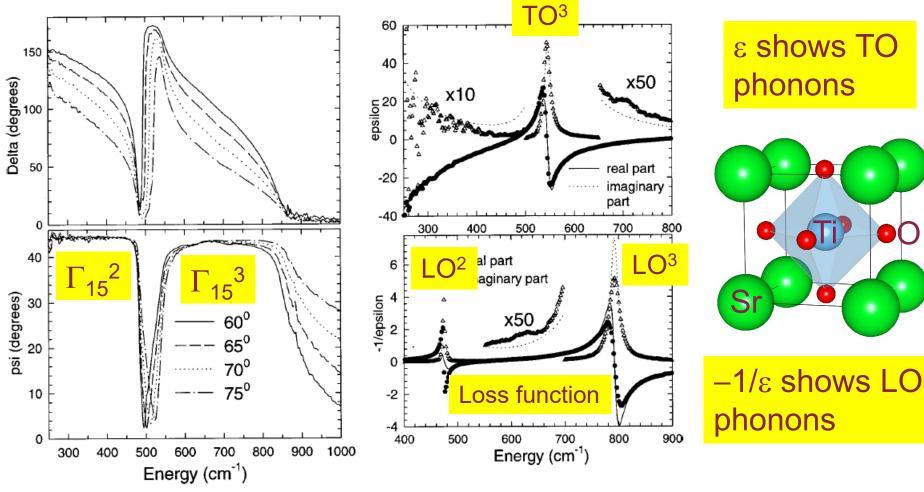
 J.R. Hardy and S.D.Smith, Phil. Mag. 69, 1163 (1961)

 Stefan Zollner, February 2019, Optical Properties of Solids Lecture 6

Two-phonon absorption (GaP)



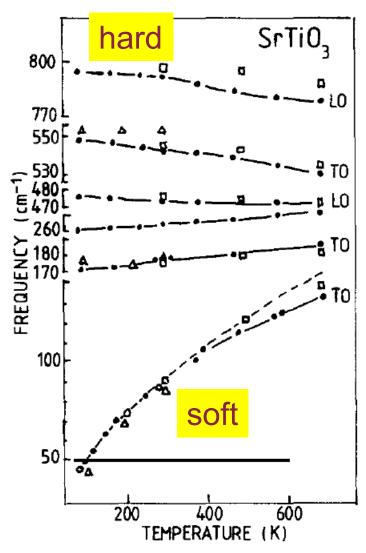
Phonons in complex oxides: Perovskites



5 atoms (SrTiO₃), 4 optical phonons at Γ , $3\Gamma_{15}(IR)+\Gamma_{25}(silent)$



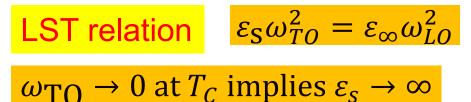
Hard and soft phonons



Typical behavior: **Hard** Phonon energy decreases with temperature.

Anomalous: **Soft** Phonon energy goes to zero at low temperature, **drives a phase transition** (collective movement of atoms)

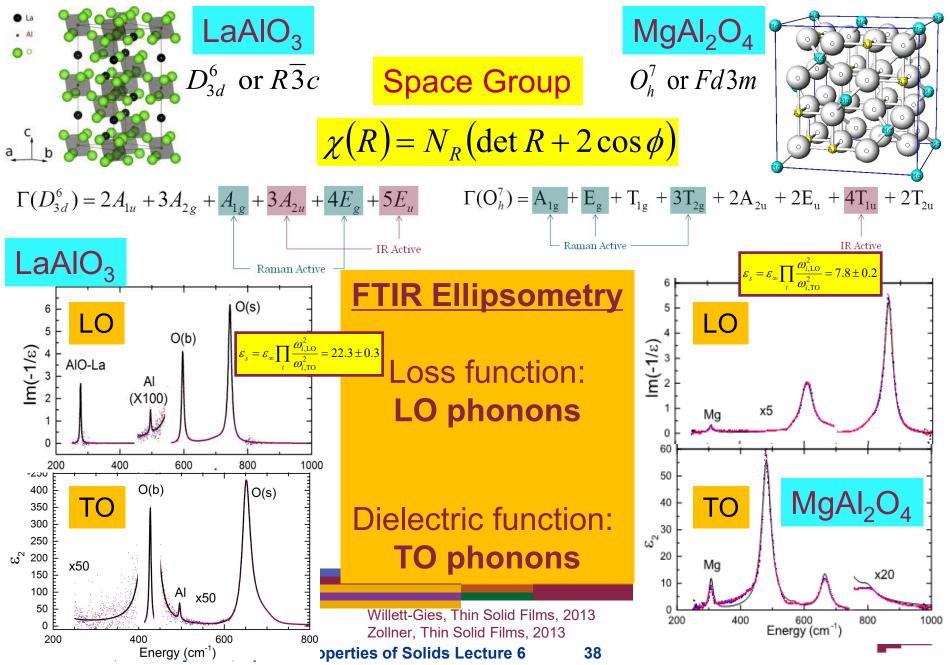
SrTiO₃ is nearly ferroelectric ($T_c \sim 0$ K).



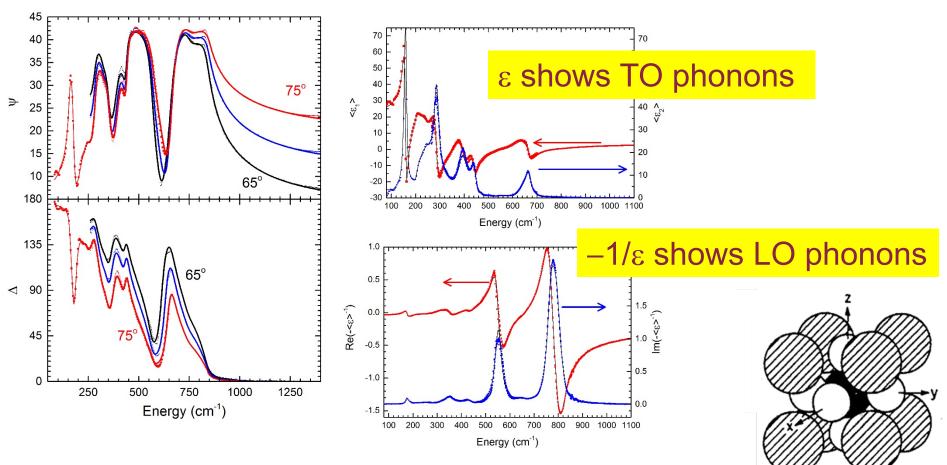


V.N. Denisov, Physics Reports 151, 1 (1987)

Phonons in more complex oxides (bulk)



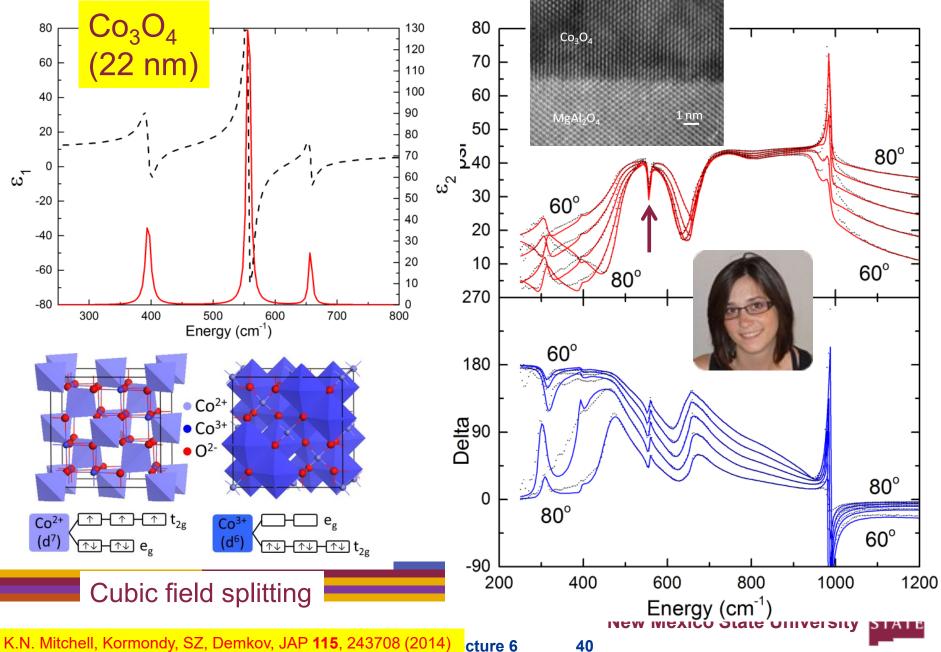
Far-infrared ellipsometry (bulk LSAT)



Disordered double perovskite $(LaAIO_3)_{0.3}(Sr_2AITaO_6)_{0.35}$ Many phonon modes. Several reststrahlen bands.

T.N. Nunley, JVSTA 34, 051507 (2016)

Phonons in more complex oxides (Co_3O_4 on spinel)



cture 6

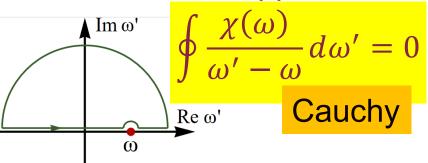
Kramers-Kronig Relations

$$\vec{P}(\vec{r},t) = \varepsilon_0 \int \chi_e(\vec{r}' - \vec{r},t'-t)\vec{E}(\vec{r}',t')dt'd^3\vec{r}'$$

Response function $\chi_e(\vec{r}' - \vec{r}, t' - t) = 0$ for t' > tThe charges cannot move before the field has been applied. <u>Kramers-Kronig relations</u> follow: $\chi(\omega)$

$$\vec{D}(\vec{k},\omega) = \varepsilon_0 \varepsilon(\vec{k},\omega) \vec{E}(\vec{k},\omega)$$

$$\varepsilon_{1}(\omega) - 1 = \frac{2}{\pi} \wp \int_{0}^{\infty} \frac{\omega' \varepsilon_{2}(\omega') d\omega'}{\omega'^{2} - \omega^{2}}$$
$$\varepsilon_{2}(\omega) = -\frac{2\omega}{\pi} \wp \int_{0}^{\infty} \frac{\varepsilon_{1}(\omega') d\omega'}{\omega'^{2} - \omega^{2}}$$



Contour integrals in complex plane: The real part of ε can be calculated if the imaginary part is known (and vice versa).

Similar Kramers-Kronig relations for other optical constants.



Analytical Properties of the Dielectric Function

Fields **E**(**r**,t) are real quantities

Onsager relation Dielectric tensor symmetric (B=0) Also from energy density. Passive materials (no optical gain)

$$\varepsilon(-\vec{k},-\omega) = \overline{\varepsilon(\vec{k},\omega)}$$
$$\frac{\varepsilon(-\omega)}{\varepsilon(-\omega)} = \overline{\varepsilon(\omega)}$$
$$\varepsilon(-\vec{k},\omega) = {}^{t}\varepsilon(\vec{k},\omega)$$
$$\varepsilon(\omega) = {}^{t}\varepsilon(\omega)$$
$$\varepsilon_{2}(\omega) \ge 0$$

Like any analytic complex function, $\epsilon(\omega)$ is defined by its zeroes and poles in the complex plane (below real axis). This implies

$$\varepsilon(\omega) = \varepsilon_{\infty} \prod_{j=1}^{N} \frac{\omega_{\text{LO},j}^2 - \omega^2 - i\gamma_{\text{LO},j}\omega}{\omega_{\text{TO},j}^2 - \omega^2 - i\gamma_{\text{TO},j}\omega}$$

R. P. Lowndes, PRB **1**, 2754 (1970).

 γ >0 (causality)

Works well for phonons and plasmons.

Also: Berreman & Unterwald, Phys. Rev. **174**, 791 (1968); Zollner, JVST B (2019).

Stefan Zollner, February 2019, Optical Properties of Solids Lecture 6

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Comparison of Lorentz and Lowndes Models

Drude-Lorentz Model

$$\varepsilon(\omega) = 1 - \sum_{i} \frac{\omega_{P,i}^2}{\omega^2 + i\gamma_{D,i}\omega} + \sum_{i} \frac{A_i \omega_{0,i}^2}{\omega_{0,i}^2 - \omega^2 - i\gamma_{0,i}\omega}$$

Lowndes Model

$$\varepsilon(\omega) = \varepsilon_{\infty} \prod_{j=1}^{N} \frac{\omega_{\text{LO},j}^2 - \omega^2 - i\gamma_{\text{LO},j}\omega}{\omega_{\text{TO},j}^2 - \omega^2 - i\gamma_{\text{TO},j}\omega}$$

R. P. Lowndes, PRB **1**, 2754 (1970).

Drude terms: Poles on the imaginary axis ($\omega_0=0$) Additional broadening parameter for LO phonon. **Lorentz identical to Lowndes model, if** $\omega_{TO}=\omega_{LO}$. Otherwise: **Frictional force allowed to vary with velocity.** Complex Lorentz amplitude, frequency-dependent damping. Lowndes model makes no assumptions about forces.

Berreman & Unterwald, Phys. Rev. 174, 791 (1968).



Summary

- Drude model explains optical response of metals.
- High reflectance below the plasma frequency.
- Interband transitions overlap with Drude absorption.
- Doped semiconductors have infrared plasma frequencies.
- Lorentz model explains infrared lattice absorption.
- TO/LO modes result in reststrahlen band.
- Multiple modes for complex crystal structures.

